SCI7661C0B/M0B

DC-DC Converter

Low Voltage Operation Products

- 95% Typical Power Efficiency
- Doubled or Tripled Output Voltage
- Internal Voltage Regulator

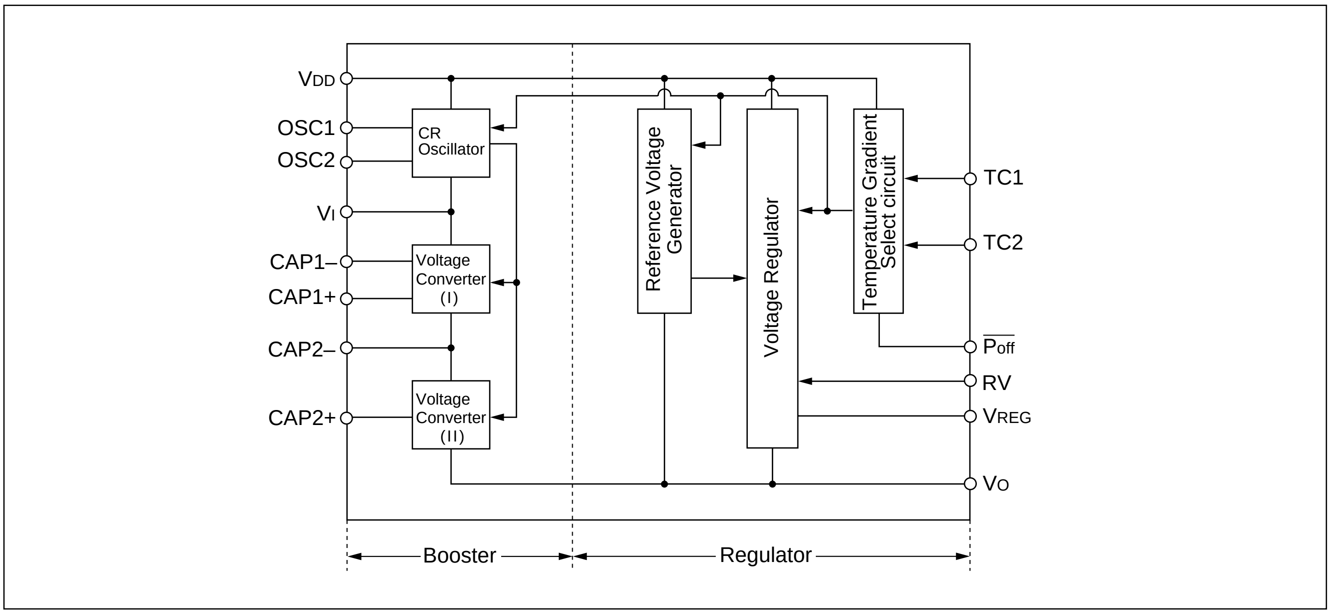
■ DESCRIPTION

The SCI7661C0B/M0B CMOS DC-DC Converter features high operational performance with low power dissipation. It consists of two major parts: the booster circuitry and the regulator circuitry. The booster generates a doubled output voltage (-3.6V to -12V) or tripled output voltage (-5.4V to -18V) from the input (-1.8 to -6V). The regulator is capable of setting the output to any desired voltage. The regulated voltage can be given one of the three threshold temperature gradients.

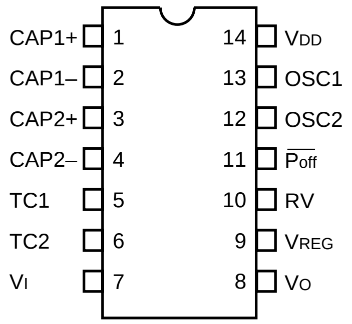
■ FEATURES

- High performance with low power dissipation
- Simple conversion of V_I (-5V) to $|V_I|$ (+5V), $2|V_I|$ (+10V), $2V_I$ (-10V) or $3V_I$ (-15V)
- On-chip output voltage regulator
- Power conversion efficiency – Typ.95%
- Temperature gradient for LCD power supply – 0.1%/°C, -0.4%/°C or -0.6%/°C
- Power off by external signals – Stationary current at power off – Max. 2µA
- Cascade connection – two device connected: V_I = -5V, V_O = -20V)
- On-chip C-R oscillator
- Package .... SCI7661C0B: DIP-14pin (plastic)
  SCI7661M0B: SOP5-14pin (plastic)
  SCI7661MBB: SSOP2-16pin (plastic)

■ BLOCK DIAGRAM



■ PIN CONFIGURATION



The same pin configuration in DIP and SOP

■ PIN DESCRIPTION

Pin name	No.	Function
CAP1+, CAP1-	1, 2	Terminal for connection of capacitor for doubler
CAP2+, CAP2-	3, 4	Terminal for connection of capacitor for tripler
TC1, TC2	5, 6	Temperature gradient selection terminal
V_I	7	Power supply terminal (negative, system supply GND)
V_O	8	Output terminal at tripling
V_{REG}	9	Regulated voltage output terminal
RV	10	Regulated voltage control terminal
$\overline{P_{off}}$	11	V_{reg} output ON/OFF control terminal
OSC2, OSC1	12, 13	Oscillation resistor connection terminal
V_{DD}	14	Power supply terminal (positive system supply V_{CC})

■ ABSOLUTE MAXIMAM RATINGS

(V_{DD} = 0V)

Rating	Symbol	Min.	Max.	Unit	Remark
Input supply voltage	V_I	-20/N	V_{DD}+0.3	V	N = 2 : Doubler N = 3 : Tripler
Input terminal voltage	V_I	V_I-0.5	V_{DD}+0.3	V	OSC1, Poff
		V_O-0.5	V_{DD}+0.3	V	TC1, TC2, RV
Output voltage	V_O	-20.0		V	
Allowable loss	P_d		300	mW	
Operating temperature	T_{opr}	-40	85	°C	Plastic package
Storage temperature	T_{stg}	-55	150	°C	
Soldering temperature and time	T_{sol}	260°C, 10s (at lead)		–	

Note: When this IC is soldered in the solder-reflow process, be sure to maintain the reflow furnace at the curve shown in “Fig. 3-5 Temperature Profile for Standard SMD Package (QFP, SOP, PLCC and etc.) of this DATA BOOK. And this IC can not be exposed to high temperature of the solder dipping.

■ ELECTRICAL CHARACTERISTICS

(V_{DD} = 0V, V_I = -5V, Ta = -40 to 85°C)

Characteristic	Symbol	Min.	Typ.	Max.	Unit	Condition
Input supply voltage	V_I	-6.0		-1.8	V	
Output voltage	V_O	-18.0			V	
	V_{REG}	-18.0		-2.6	V	$R_L = \infty$, R_{RV} = 1MΩ V_O = -18V
Regulator operating voltage	V_O	-18.0		-3.2	V	
Booster current consumption	I_{opr1}		40	80	µA	$R_L = \infty$, R_{OSC} = 1MΩ
Regulator current consumption	I_{opr2}		5.0	12.0	µA	$R_L = \infty$, R_{RV} = 1MΩ V_O = -15V
Stationary current	I_Q			2.0	µA	TC2 = TC1 = V_O, $R_L = \infty$
Oscillation frequency	f_{OSC}	16	20	24	kHz	R_{OSC} = 1MΩ
Output impedamce	R_{OUT}		150	200	Ω	I_O = 10mA
Booster power conversion efficiency	Peff	90	95		%	I_O = 5mA
Regulated output voltage fluctuation	$\frac{\Delta V_{REG}}{\Delta V_O \cdot V_{REG}}$		0.2		%/V	-18V < V_O < -8V V_{REG} = -8V, $R_L = \infty$, Ta = 25°C

EPSON

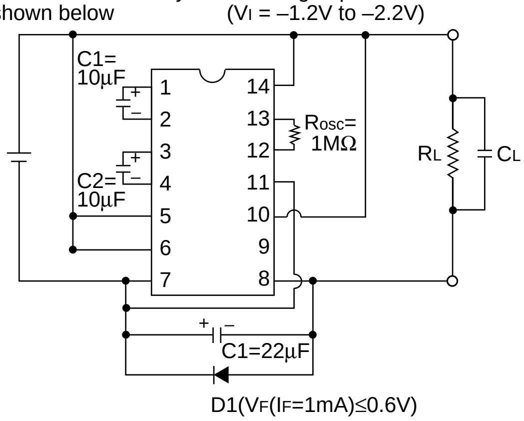
Characteristic	Symbol	Min.	Typ.	Max.	Unit	Condition
Regulated output load fluctuation	$\frac{\Delta V_{REG}}{\Delta I_O}$		5.0		Ω	V_O = -15V, V_{REG} = -8V, Ta = 25°C 0 < I_O < 10mA, TC1 = V_{DD} TC2 = V_O
Regulated output saturation resistance	R_{SAT}		8.0		Ω	$R_{SAT} = \Delta(V_{REG} - V_O) / \Delta I_O$ 0 < I_O < 10mA, RV = V_{DD}, Ta = 25°C
Reference voltage	V_{RV0} V_{RV1} V_{RV2}	-2.3 -1.7 -1.1	-1.5 -1.3 -0.9	-1.0 -1.1 -0.8	V	TC2 = V_O, TC1 = V_{DD}, Ta = 25°C TC2 = TC1 = V_O, Ta = 25°C TC2 = V_{DD}, TC1 = V_O, Ta = 25°C
Temperature Gradient	C_{T0} C_{T1} C_{T2}	-0.25 -0.5 -0.7	-0.1 -0.4 -0.6	-0.01 -0.3 -0.5	%/°C	$CT = \frac{\lvert V_{REG}(50°C) \rvert - \lvert V_{REG}(0°C) \rvert}{50°C - 0°C} \times \frac{1}{\lvert V_{REG}(25°C) \rvert} \times 100$
Input leakage current	I_L			2.0	µA	$\overline{Poff}$, TC1, TC2, OSC1, RV pins

■ RECOMMENDED OPERATING CONDITIONS

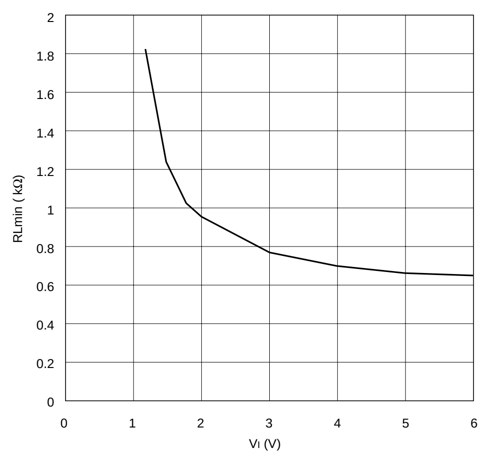
(Ta = -30 to 85°C)

Condition	Symbol	Min.	Max.	Unit	Remark
Booster start voltage	V_{STA}		-1.8	V	R_{OSC} = 1MΩ, $C_3 \geq$ 10µF*1 $C_L/C_3 \leq$ 1/20, Ta = -20 to 85°C
Booster stop voltage	V_{STP}	-1.8		V	R_{OSC} = 1MΩ
Output load resistance	R_L	R_L Min.*2		Ω	
Output load current	I_{OUT}		20	mA	
Oscillation frequency	f_{OSC}	10	30	kHz	
Extarnal resistance for oscillation	R_{OSC}	680	2000	kΩ	
Capacitor for booster	C_1, C_2, C_3	3.3		µF	
Regulated output adjustable resistance	R_{RV}	100	1000	kΩ	

*1: Recommended circuitry in low voltage operation is shown below (V_I = –1.2V to –2.2V)



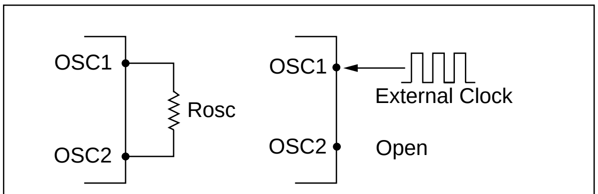
RL Min. depends on input voltage as shown below.



■ CIRCUIT DESCRIPTION

● C-R Oscillator

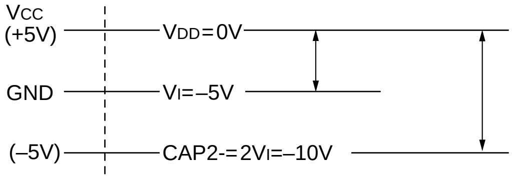
The SCI7661C0B/M0B contains a C-R oscillator for internal oscillation. It consists of an external resistor R_{OSC} connected between the OSC1 pin and OSC2 pin.



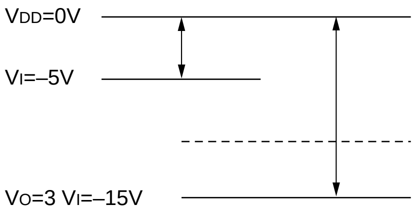
C-R Oscillation External Clock Operation

● Voltage Converters

The voltage converters double/triple the input supply voltage (V_I) using clocks generated by the C-R oscillator.



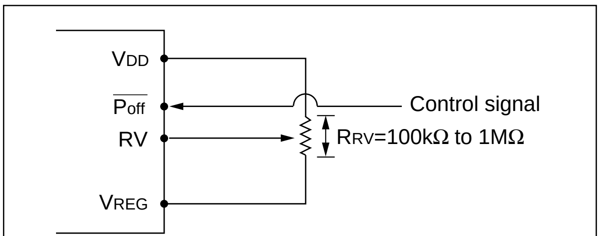
Typical Doubled Voltage Relations



Typical Tripled Voltage Relations

● Reference Voltage Generator and Voltage Regulator

The reference voltage generator produces reference voltage needed for operation of regulator circuit. The voltage regulator is used to regulate a boosted output voltage and its circuit contains a power-off function which uses signals from the system for on-off control of the Vreg output.



Voltage Regulator

● Temperature Gradient Selector Circuit

The SCI7661C0B/M0B provides the V_{REG} output with a temperature gradient suitable for LCD driving.

(between V_{DD} and V_{REG})

● Temperature Gradient Assignment

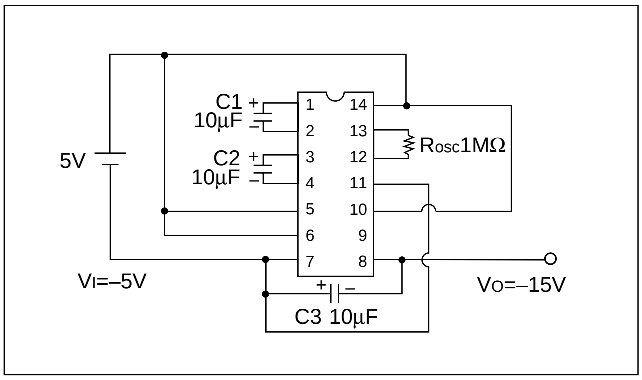
$\overline{Poff}$	TC2	TC1	Temp. Gradient	V_{REG} Output	CR oscillation	Remarks
1(V_{DD})	L(V_O)	L(V_O)	-0.4%/°C	ON	ON	
1	L	H(V_{DD})	-0.1%/°C	ON	ON	
1	H(V_{DD})	L	-0.6%/°C	ON	ON	
1	H	H	-0.6%/°C	ON	OFF	Cascade connection
0(V_I)	L	L	–	OFF (Hi-Z)	OFF	
0	L	H	–	OFF (Hi-Z)	OFF	
0	H	L	–	OFF (Hi-Z)	OFF	
0	H	H	–	OFF (Hi-Z)	ON	Without regulation

Note: The potential at Low level is different between the $\overline{Poff}$ pin and the TC1/TC2 pin.

■ BASIC EXTERNAL CONNECTION

● Voltage Doubler and Tripler

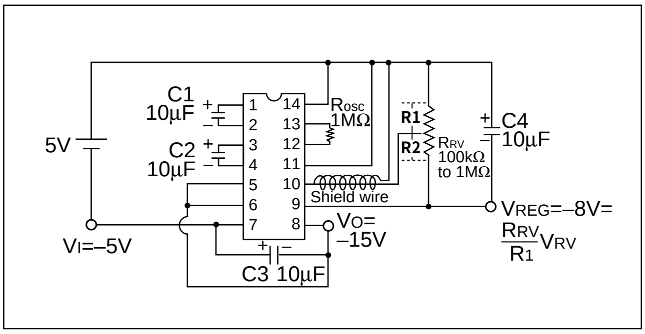
A doubled voltage can be obtained at V_O (CAP2-) by disconnecting capacitor C_2 from the tripler configuration and shorting CAP2- (pin 4) and V_O (pin 8).



Voltage Tripler

● Voltage Tripler + Regulator

V_{REG} output is given a temperature gradient, after boosted output V_O regulated. In this connection, both V_O and V_{REG} can be taken out at the same time.

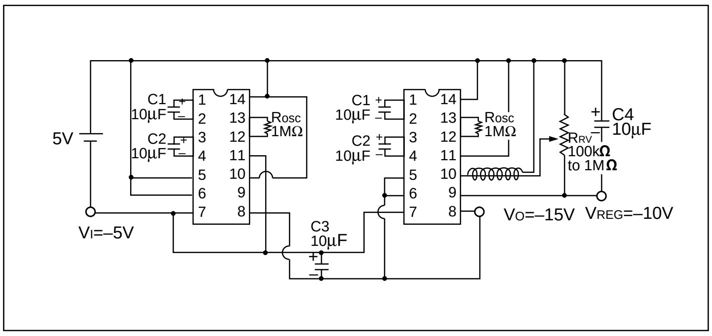


Tripler + Regulator
(-0.4%/°C selected as temperature gradient)

● Parallel Connection

Parallel connections of n circuits can reduce R_{out} to about 1/n, that output impedance R_{out} can be reduced by connecting serial configuration. A single smoothing capacitor C_3 can be used commonly for all parallely connected circuit.

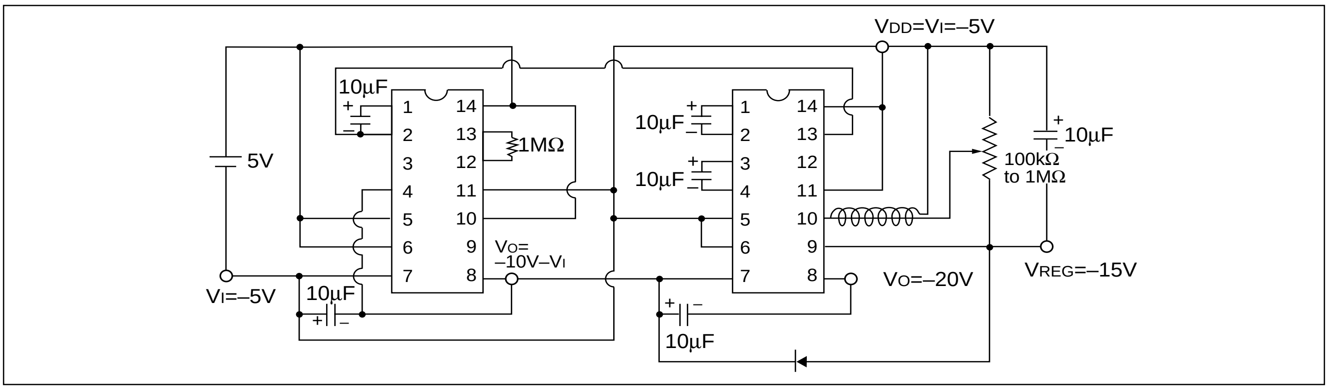
In parallely connection, a regulated output can be obtained by applying the regulation circuit to only one of the n parallely connected circuit.



Parallel Connection

● Cascade Connection

Cascade Connection of SCI7661C0B/M0B (by connecting V_{IN} and V_{OUT} of one stage to V_{DD} and V_I respectively of the next stage) further increase the output voltage. Note, however, that the serial connection increases the output impedance.

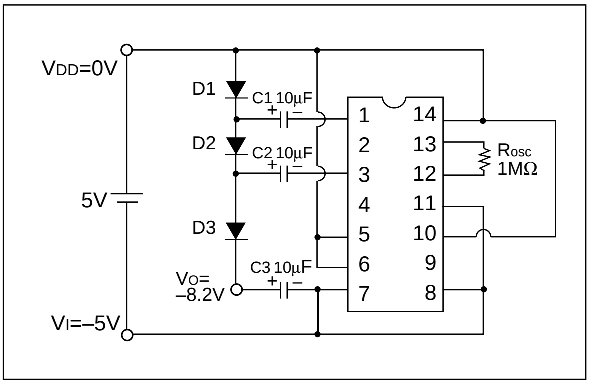


Serial Connection

● **Positive Voltage Conversion**

The input voltage can be doubled or tripled toward the positive side. (In the doubler configuration, capacitor C2 and diode D3 are disconnected and the diode D3 shorted at the both ends.) In this case, however, the output voltage decrease by VF (forward voltage).

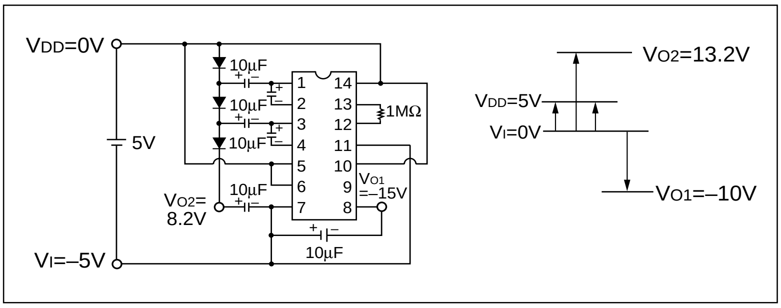
For example V_{DD} = 0V, V_I = -5V and V_F = 6.0V, then V_O = 10V -3 × 0.6V = 8.2V (if doubled, 5V -2 × 0.6V = 3.8V)



Positive Voltage Conversion D1, D2, D3: Shottky diodes with small VF are recommended.

● **Negative Voltage Conversion + Positive Voltage Conversion**

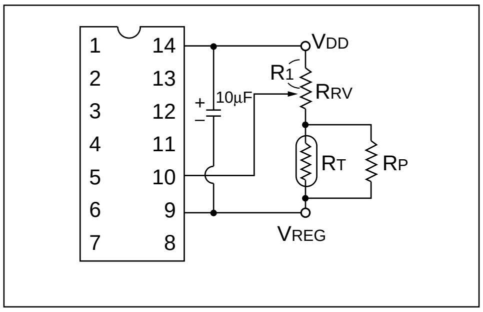
This circuit produces outputs of -15V and +8.2V from the -5V input. Note that this configuration causes higher output impedance than in a single function (negative or positive voltage converter.)



Negative Voltage Conversion + Positive Voltage Conversion

● **Changing the Temperature Gradient through Use of External Temperature Sensor (Thermistor)**

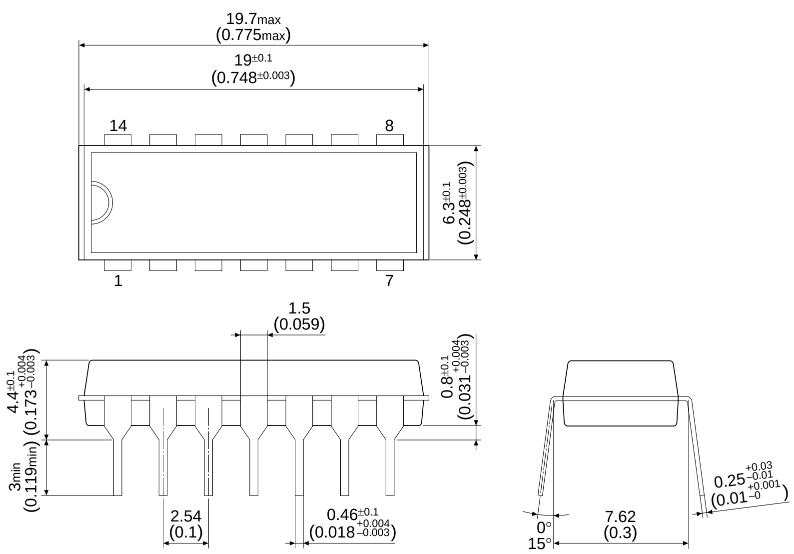
The SCI7661C0B/M0B has a temperature gradient selector circuit in its regulator. It selects any one of the three gradients: -0.1%/°C, -0.4%/°C and -0.6%/°C. Itis necessary that the temperature gradient can be changed to any other value by connecting a thermistor in series to the output voltage control resistor RRV.



Example of Change of Temperature Gradient

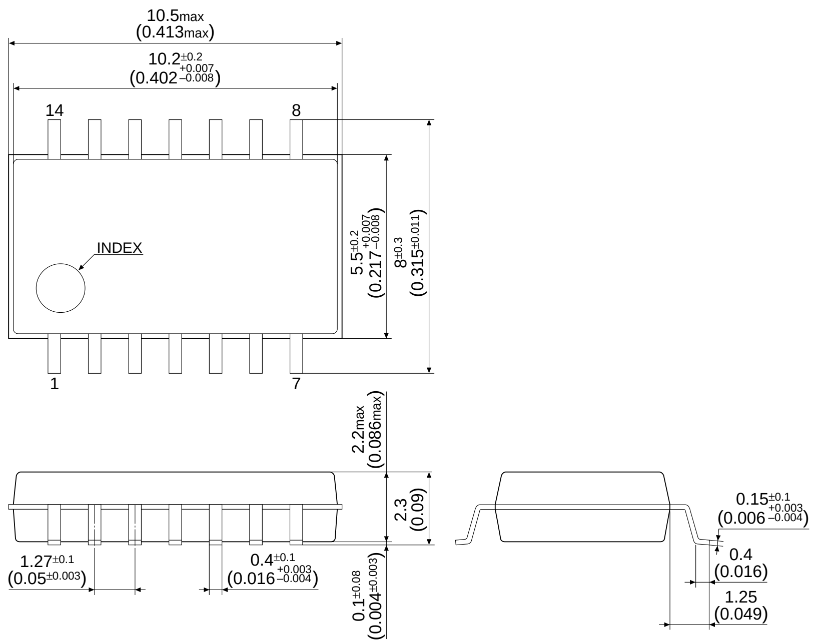
■ **PACKAGE DIMENSIONS**

Plastic DIP-14pin



Unit : mm
(inch)

Plastic SOP5-14pin



Unit : mm
(inch)

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